CONTENTS

Overview .............................................................................................................1
by Shinichi Nishizawa

Technical Reports

SiC Power Module for Automotive .................................................................3
by Hideo Komo and Shoichi Orita

TH-Series: 7th Generation IGBT Modules for High-frequency Switching in Industrial Operation ............................................................7
by Satoshi Kawabata and Hiroki Muraoka

The Investigation of Humidity Absorption Behavior of Silicone Gel in HVIGBT Modules .................................................................11
by Kenji Hatori and Wakana Noboru

Built-in BSD-Function 600V High Voltage Integrated Circuit “M81777FP” ...............................................................15
by Yo Habu and Shohei Sano

Development of SiC Trench MOSFET with Novel Structure Enabling Lower Losses .................................................................19
by Katsutoshi Sugawara and Yutaka Fukui

Precis

Mitsubishi Electric’s power modules, which employ the latest chip and package technology, realize ideal power electronics systems thanks to their high quality, low loss, and excellent noise performance.